


	<h2>RFD14N05L</h2>
	<p><b>Hersteller-Teilenummer:</b> RFD14N05L</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 50V 14A I-PAK</p> <p><b>Datenblätter:</b>  <a href="#">RFD14N05L.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 17071 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	RFD14N05L
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 50V 14A I-PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	17071 pcs Stock
Hersteller Standard Vorlaufzeit	6 Weeks
detaillierte Beschreibung	N-Channel 50V 14A (Tc) 48W (Tc) Through Hole TO-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	TO-251AA
Verlustleistung (max)	48W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 14A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	670pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	±10V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)






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Sie können auch interessiert sein:

 <p><b>RFD12N06RLESM9A</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p><b>RFD14N05LSM</b> Fairchild/ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>	 <p><b>RFD14N05</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 14A I-PAK</p>	 <p><b>RFD14N05LSM RFD14N05L</b> FAIRCHILD/ FAIRCHILD/ 252251</p>
 <p><b>RFD12N06RLESM9A</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p><b>RFD14N05L</b> Fairchild/ON Semiconductor MOSFET N-CH 50V 14A I-PAK</p>	 <p><b>RFD14N05LSM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>	 <p><b>RFD14N05LM</b> FAIRCHI RFD14N05LM FAIRCHI</p>

### heiße Teile

Mehr

 RFD10N05SM96	 RFD10P03L-251	 RFD10P03LSM	 RFD10P03LSM	 RFD10P05
 RFD12N06LE	 RFD12N06LESM	 RFD12N06REL	 RFD12N06RLE	 RFD12N06RLE
 RFD12N06RLESM	 RFD12N06RLESM9A	 RFD12N06RLESM9A	 RFD14N05	 RFD14N05
 RFD14N05L	 RFD14N05LSM	 RFD14N05LSM	 RFD14N05LSM9A	 RFD14N05LSM9A
 RFD14N05SM	 RFD14N05SM	 RFD14N05SM9	 RFD14N05SM9A	 RFD14N05SM9A
 RFD15N05	 RFD15N05LSM	 RFD15N06LE	 RFD15N06LESM	 RFD15P05
 RFD15P05	 RFD15P05SM	 RFD15P05SM	 RFD15P05SM9A	 RFD15P06
 RFD15P06LSM	 RFD15P06SM	 RFD15P06SM9AS2463	 RFD16N02	 RFD16N02L
 RFD16N02LSM	 RFD16N02LSM9A	 RFD16N03L	 RFD16N03LSM	 RFD16N03LSM9A
 RFD16N05	 RFD16N05	 RFD16N05L	 RFD16N05LSM	 RFD16N05LSM

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